Nanopatterning of carbonaceous structures by field-induced carbon dioxide splitting with a force microscope

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(Received 4 December 2009; accepted 8 March 2010; published online 5 April 2010)

We report a tip-based nanofabrication method to generate carbon nanopatterns. The process uses the field-induced transformation of carbon dioxide gas into a solid material. It requires the application of low-to-moderate voltages \(\sim 10–40\) V. The method allows us to fabricate sub-25 nm dots and it can be up scaled to pattern square centimeter areas. Photoemission spectroscopy shows that the carbon is the dominating atomic species of the fabricated structures. The formation of carbon nanostructures and oxides by atomic force microscope nanolithography expands its potential by providing patterns on the same sample with different chemical composition. © 2010 American Institute of Physics. [doi:10.1063/1.3374885]

The control and manipulation of electric fields at the nanoscale has enabled the emergence of a flexible atomic force microscope (AFM) nanolithography called local oxidation.1–4 This method is based on the field-induced activation of molecules within a water meniscus and the subsequent oxidation of the sample surface.5–7 Local oxidation nanolithography has been applied to fabricate nanoscale electronic devices,8,9 microelectromechanical systems10 or templates for the direct growth of single-molecule magnets11 or metallic nanoparticles.12,13 Local oxidation is compatible with imprinting techniques, thus enabling the patterning of large areas has been demonstrated.4,14–16

The method has been extended to other liquids such as ethanol,17 octane,18,19 or hexadecane.7,20 Furthermore, field-assisted nanopatterning has been performed on polymer surfaces21 or by inducing the transfer of material from the tip to the surface.22

The interest in fabricating structures by AFM nanolithography of a chemical composition different from oxides, in particular carbon compounds, lies in its chemical complementarity. Thus heterogeneous nanopatterns could be generated where the chemical activity of a given region depends on the process used to fabricate the structure (oxidation versus carbon formation). Furthermore, the fabrication of nanopatterns of carbon materials could be simplified if the source of material comes directly from a gas. We hypothesize that the field-induced activation of liquid molecules can be extended to transform stable gases such as carbon dioxide in ambient conditions.

We report on the transformation of carbon dioxide into a solid carbonaceous material that can be deposited with nanoscale accuracy over a silicon surface. The process takes place at room temperature and uses low-to-moderate voltages \(\sim 10–40\) V. The process exploits the high electric fields that can be generated with a nanoscale asperity \((\sim 1–30\) V/nm\). The approach can be performed with a single nanoscale asperity (AFM) and with a macroscopic surface patterned (stamp) with billions of nanoscale asperities.

The physical process [Fig. 1(a)] exploits the proximity effect between a flat surface and a sharp protrusion. This

FIG. 1. (Color) (a) Schematics of the activation process with an AFM operated in amplitude modulation (noncontact regime). (b) AFM image of a sequence of dots generated by applying 21 V for, left to right, 0.1, 0.5, 1, 10, 50, and 100 ms, 1s and 2s. (c) Sequence of dots generated by applying (from left to right) 20, 22, 24, 26, 28, 30, 34, and 36 V pulses for 0.1 ms. (d) AFM image of a carbonaceous film formed after the activation of CO2 gas with a stamp. Scale bar of 200 nm in (b) and (c).
are generated by applying short voltage pulses
either modifying the distance or the voltage. The field
experiments the field can be easily determined and varied by
voltage pulse is applied. Figures1
tip is placed 2–5 nm above the silicon surface while the
carbon dioxide gas in a single asperity interface. The AFM
applied voltage. At the flat surface, the field
of dots generated after the activation of CO2. Sub-25 nm dots
Ft
The field,
where
R
is the effective radius of the protrusion and
V
is the applied voltage. At the flat surface, the field
Ft
is,
\[ F_t = \frac{1}{K_t} \frac{V}{R} \] 
(1)
where
\( K_t \) and \( K_s \) are geometrical factors.\(^{23,25} \) In the AFM
experiments the field can be easily determined and varied by
either modifying the distance or the voltage. The field has
been changed from 0.1 to 30 V/nm.

Figure 1(a) shows the experimental set-up to activate
carbon dioxide gas in a single asperity interface. The AFM
tip is placed 2–5 nm above the silicon surface while the
voltage pulse is applied. Figures 1(b) and 1(c) show a series
of dots generated after the activation of CO2. Sub-25 nm dots
are generated by applying short voltage pulses (~0.1 ms).

Similarly to what happens with local oxidation experiments,\(^{18-17} \) the process can be upscaled by using a pat-
terned stamp. Figure 1(d) shows a pattern formed after the
activation of carbon dioxide with a gold-coated stamp pat-
terned with an array of parallel lines 760 nm apart. The depo-
sition occurs on the positively biased surface. The periodic pattern reflects the periodicity of the stamp and was gener-
ated by applying a voltage pulse of 36 V for 60 s. The fab-
ricated structures act as resists with respect to hydrogen fluo-
ride (HF) vapor exposure.

To optimize the conversion of CO2, we have varied the
voltage pulse strength and duration with an amplitude modu-
lation AFM operated in noncontact mode.\(^{26,27} \) Figure 2(a)
shows the cross-sections of some dots obtained after the
application of a voltage pulse of 21 V (pulse times ranging
from 10\(^{-4}\) to 2 s). For short pulse times (≤0.1 s), the dot
height increases linearly with time. A sudden increase in size
occurs at longer pulses. The diameter of the dots changes
from 90 to 180 nm upon going from 0.1 to 2 s. That implies
a factor ~10 increase in the volume. The size dependence of
the dots on voltage shows a monotonic increase [Fig. 2(b)].
The above experiment was performed at fixed pulse duration
of 10\(^{-4}\) s, while the voltage was changed from 20 to 36 V in
2 V steps.

The chemical composition has been characterized by
photoemission spectroscopy experiments (XPS) at two dif-
ferent points. The first is located in a region where the acti-
vation of CO2 took place (patterned region). The second is in
a region where no conversion was produced (reference re-
gion). The wide XPS spectrum of the patterned region re-
veals four different peaks [Fig. 3(a)]. The highest signals are
centered at the O 1s and C 1s core-level binding energies.
The other peaks correspond to the emission from the Si 2s
and 2p core levels. The atomic concentrations extracted from
the integrated intensities of O 1s and C 1s peaks in the pat-
terned spectrum are, respectively, 2.2 and 6.4 times higher
than in the reference. The presence of C and O on the top of
the reference region is due to the air exposure of the sample
surface. The spectroscopy data also indicate that the carbo-
aceous deposits contain six times more C than O. At the
same time, the atomic concentration of Si is smaller by a

FIG. 2. (Color online) (a) Sequence of dots generated by applying 21 V for
different pulse times [see caption of Fig. 1(b)]. (b) AFM image of a se-
quence of dots generated by the application of different voltages for 0.1 ms
[see caption of Fig. 1(c)]. The arrows in Figs. 1(b) and 1(c) indicate the
position of the cross-sections.

FIG. 3. (Color) (a) Wide x-ray photoemission spectrum performed on
the carbonaceous film and the reference regions. (b) XPS C 1s core-level spec-
trum of a patterned region and the deconvolutions for the carbon–oxygen
bonds (blue) and the C–C and/or C–H bonds (red). (c) XPS O 1s core-level
spectrum of a patterned region and the deconvolutions for the carbon-
oxygen bonds (blue) and the O–Si bonds (red). In (b) and (c) The filled dots
joined by a continuous line are the experiments.
factor of 1.4 because the carbonaceous material on the top of the silicon surface reduces the Si signal.

The deconvolution of the higher energy resolution spectrum of the C 1s core level [Fig. 3(b)] reveals two dominant components at 285.2 and 286.7 eV. The binding energy of 285.2 eV corresponds to either C–C or to C–H bonds in the sp³ tetrahedral configuration, whereas the component located at 286.7 eV corresponds to carbon–oxygen bonds. The amount of carbon in the patterns has increased 650% relative to the unpatterned regions. The increase in the carbon concentration is mostly due to C–C bonds.

The resolution spectrum of the O 1s core level has two components [Fig. 3(c)]. The first is centered at a binding energy of 532.6 eV. It shows the presence of Si oxides (mainly SiO₂). The second component is centered at 532.3 eV and reveals the presence of O=C bonds in agreement with the spectrum measured at the C 1s level. The resolution spectrum did not reveal the presence of O=C bonds.

Quantum chemical calculations show that the purely electronic energy barrier for dissociation, ΔE, of one of the two OC⋯O bonds is ~6.1 eV, at zero field, and ~3.25 eV at 40 V/nm. At 20 V/nm the barrier is ~5.3 eV and the reaction becomes exothermic with the products (CO, O) lower in energy than the reactants (CO₂). It can be proposed that the energy is spent to overcome the barrier for dissociation. As a function of the experimental conditions, or in other words of the field experienced by CO₂ when it breaks apart, different amounts of energy are used.

The transformation of CO₂ can be separated into three major steps. The first step is the capture of CO₂ in the gap region between the two electrodes. The second step is the activation of the molecules, and third step is the formation of the carbonaceous deposit. The first step is a field-induced diffusion process. The electric field polarizes the molecule and the resulting dipole moment interacts with the field. The potential energy of a CO₂ molecule under the influence of the field can be approximated as,

\[ U = U_0 - \frac{1}{2} \alpha E^2, \]  
(3)

where \( \alpha = 2.93 \times 10^{-40} \text{C}^2 \text{m}^2 \text{J}^{-1} \) is the static polarizability of the CO₂ and \( U_0 \) is its energy in the absence of the field. As a consequence in a nonuniform field the molecules experience a polarization force toward the conductive surfaces. The high electric fields trap the CO₂ between the conductive surfaces, and increase the gas density. We can estimate the change in pressure, \( p \), between the electrodes as, \( p = p_0 \exp(\Delta U/k_B T) \), where \( p_0 \) is the pressure at zero field. For a field of 10 V/nm, we obtain \( \Delta U = 92 \text{meV} \), which gives \( p \approx 36p_0 \) (\( T = 298 \text{K} \)). Higher pressures imply higher collision rates between the gas molecules.

In a third step, the molecules diffuse to the solid where they become adsorbed. There the dissociated and activated molecules react with other molecules to form the carbonaceous material. The resulting material is a carbon compound with the presence of some oxygen. This leads to the formation of carbonaceous nanopatterns that are resistant to HF etching.

We are very grateful to José M. Soler for their insightful and motivating comments. We acknowledge financial supports from the Ministerio de Ciencia, Investigación e Innovación (Grant Nos. MAT2009-08650; CTQ2007-31076-E; and MAT2008-06765).